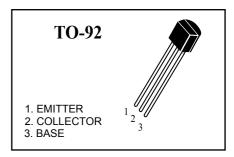


A1015

# **PNP General Purpose Transistors**

**Pb** Lead(Pb)-Free



#### MAXIMUM RATINGS\* (T<sub>A</sub>=25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V <sub>CEO</sub>	-50	V
Collector-Base Voltage	V <sub>CBO</sub>	-50	V
Emitter-Base Voltage	V <sub>EBO</sub>	-5.0	V
Collector Current Continuous	I <sub>C</sub>	-150	mA
Total Device Dissipation T <sub>A</sub> =25°C	P <sub>D</sub>	0.4	W
Junction Temperature	Тյ	+150	°C
Storage Temperature	T <sub>STG</sub>	-55 to + 150	°C

<sup>\*</sup>These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

#### **ELECTRICAL CHARACTERISTICS**

Characteristics		Min	Max	Unit
OFF CHARACTERISTICS				
Collector-Base Breakdown Voltage, $I_C = -100\mu\text{A}$ , $I_E = 0$	V(BR) <sub>CBO</sub>	-	-50	V
Collector-Emitter Breakdown Voltage, $I_C = -0.1$ mA, $I_B = 0$	V(BR) <sub>CEO</sub>	-	-50	V

Collector-Emitter Breakdown Voltage, $I_C = -0.1$ mA, $I_B = 0$		V(BR) <sub>CEO</sub>	-	-50	V
	Emitter-Base Breakdown Voltage, $I_E = -100\mu A$ , $I_C = 0$	V(BR) <sub>EBO</sub>	-	-5.0	V
	Collector Cut-off Current, $V_{CB} = -50V$ , $I_E = 0$	I <sub>CBO</sub>	-	-0.1	μΑ
	Collector Cut-off Current, $V_{CE} = -50V$ , $I_B = 0$	I <sub>CEO</sub>	-	-0.1	μΑ
	Emitter Cut-off Current, $V_{FB} = -5.0V$ , $I_C = 0$	I <sub>ERO</sub>	_	-0.1	uА

# A1015



#### $\pmb{ELECTRICAL\ CHARACTERISTICS}\ (T_{A} = 25\ ^{\circ}\!C\ unless\ otherwise\ noted)\ (Countinued)}$

Characteristics	Symbol	Min	Тур	Max	Unit	l
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#### **ON CHARACTERISTICS**

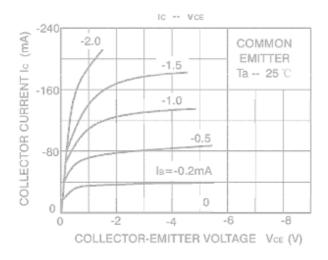
DC Current Gain V <sub>CE</sub> =-6.0V, I <sub>C</sub> =-2.0mA	h <sub>FE1</sub>	70	-	400	-
Collector-Emitter Saturation Voltage I <sub>C</sub> =-100mA, I <sub>B</sub> =-10mA	V <sub>CE(sat)</sub>	-	-	-0.3	V
Base-Emitter Voltage I <sub>C</sub> =-100mA, I <sub>B</sub> =-10mA	V <sub>BE(sat)</sub>	-	-	-1.1	V
TransitionFrequence $V_{CE} = -10V$ , $I_C = -1mA$ , $f = 30MHz$	f <sub>T</sub>	80	-	-	MHz
Collector Output Capacitance $V_{CB} = -10V$ , $I_E = 0$ , $f = 1MHz$	Cob	-	19	-	pF
Noise Figure $V_{CE} = -6V$ , $I_C = -0.1$ mA, $Rg = 10$ k $\Omega$ , $f = 1$ KMHz	NF	-	-	6	dB

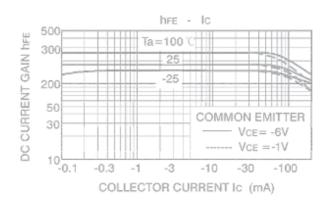
#### CLASSIFICATION OF h<sub>FE1</sub>

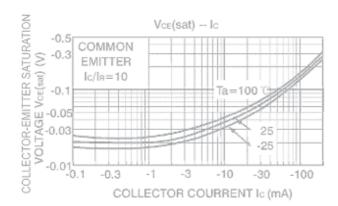
Rank	0	Υ	GR
Range	70-140	120-240	200-400

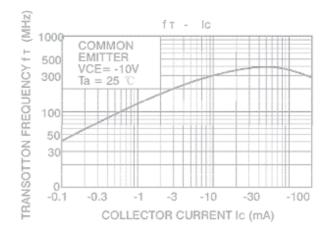


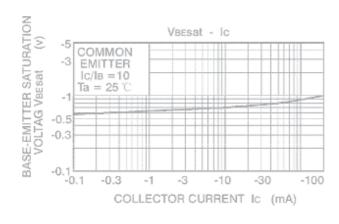
# **Typical Characteristics**

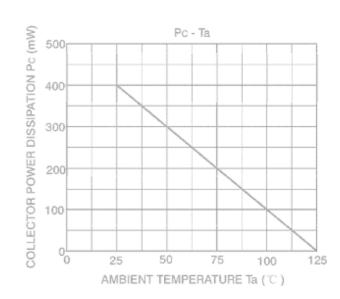






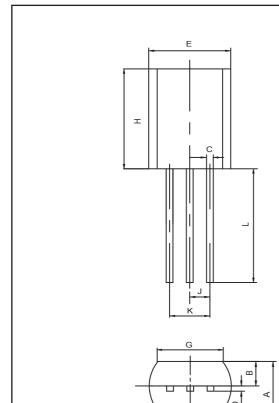






### **TO-92 Outline Dimensions**

unit:mm



TO-92				
Dim	Min	Max		
A	3.30	3.70		
В	1.10	1.40		
C	0.38	0.55		
D	0.36	0.51		
E	4.40	4.70		
G	3.43	-		
H	4.30	4.70		
J	1.270TYP			
K	2.44	2.64		
L	14.10	14.50		